NSN 5961-01-071-8545

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-071-8545 **Inclosure Material:** Plastic **Overall Length:** 0.370 inches **Overall Diameter:** 0.250 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-201ad **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 reverse voltage, peak **Current Rating Per Characteristic:** 3.00 amperes forward current, average and 80.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: